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5 SEM TDC PHY M 4

2017

(November)

PHYSICS

(Major)

Course : 504

(**Electronics**)

Full Marks : 60

Pass Marks : 24/18

Time : 3 hours

*The figures in the margin indicate full marks
for the questions*

1. Choose the correct answer :

1×6=6

(a) The frequency of ripple voltage at the output of a full-wave rectifier operating from a 50 Hz supply is

(i) 50 Hz

(ii) 100 Hz

(iii) 150 Hz

(iv) 200 Hz

(Turn Over)

(2)

- (b) A semiconductor is formed by
- (i) ionic bond
 - (ii) electrovalent bond
 - (iii) covalent bond
 - (iv) coordinate bond
- (c) The voltage gain of a transistor is highest in the configuration
- (i) CB
 - (ii) CC
 - (iii) CE
 - (iv) emitter follower
- (d) The CMRR is defined as the ratio of
- (i) differential voltage gain to current gain
 - (ii) current gain to differential voltage gain
 - (iii) differential voltage gain to common-mode voltage gain
 - (iv) None of the above

(3)

- (e) The oscillator which produces non-sinusoidal waveform is
- (i) tuned collector
 - (ii) Hartley oscillator
 - (iii) relaxation oscillator
 - (iv) crystal oscillator
- (f) The minimum number of NOR gates required to design an XOR gate is
- (i) 3
 - (ii) 4
 - (iii) 5
 - (iv) 7

2. Answer the following questions : $2 \times 6 = 12$

- (a) A diode having forward resistance of 50Ω supplies power to a load resistance 1200Ω from a 20 V (r.m.s.) source. Calculate d.c. load current.
- (b) Explain the difference between a semiconductor and conductor from band diagram.

- (c) What is thermal stabilization?
- (d) An amplifier has a voltage gain of -100 . The feedback ratio is -0.04 . Find the voltage gain with feedback.
- (e) State Barkhausen criterion for sustained oscillation.
- (f) Draw the logic circuit of the following Boolean equation :

$$W = (X + YZ)(Y + \bar{Z}X)$$

3. (a) Distinguish between Zener diode and ordinary junction diode. Explain the action of Zener diode as voltage regulator. Draw the V - I characteristics of Zener diode and explain it. $2+3+2=7$
- (b) Differentiate intrinsic and extrinsic semiconductor on the basis of energy-band diagram. Explain the mechanism of current flow under forward and reverse biased conditions. $3+4=7$

Or

Draw the circuit diagram of a bridge rectifier with shunt capacitor filter and explain its operation. Derive the expression for ripple factor and efficiency without filter. $3+4=7$

(Continued)

4. (a) Find the gain of negative feedback amplifier with block diagram. Discuss the effect of negative feedback on amplifier characteristics. $3+4=7$

Or

What are class-A and class-B amplifier? Draw the circuit diagram of a push-pull class-B transistor amplifier and explain its operation. Find an expression for the maximum efficiency of the amplifier. $2+5=7$

- (b) Explain the mechanism of current flow in a p - n - p transistor. 3

5. (a) Explain how an OP-AMP can be used as integrator. 3

- (b) Draw the circuit diagram of Hartley oscillator and explain its operation. Find the expression for frequency of oscillation. $2\frac{1}{2}+2\frac{1}{2}=5$

Or

What is an IC? Explain the steps involved in fabricating a diode in an IC. $1+3+1=5$
Write the limitation of IC.

(Turn Over)

6. (a) Realize an OR gate using $p-n$ diode and explain its operation.

(b) Simplify the following Boolean expression :

$$(\overline{AC} + B)(\overline{A} + \overline{C})$$

(c) Discuss the working of half adder with its logic diagram and truth table.

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